

R6046FNZ1

Nch 600V 46A Power MOSFET

V_{DSS}	600V
R _{DS(on)} (Max.)	0.098Ω
I _D	46A
P_D	694W

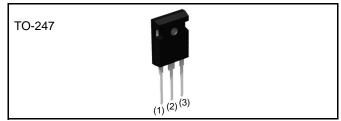
Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Gate-source voltage (V_{GSS}) guaranteed to be $\pm 30V$.
- 4) Drive circuits can be simple.
- 5) Parallel use is easy.
- 6) Pb-free lead plating; RoHS compliant

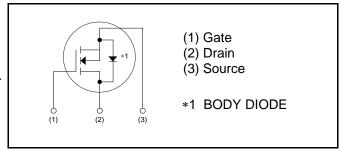
Application

Switching Power Supply

Outline



●Inner circuit



Packaging specifications

	Packaging	Tube			
	Reel size (mm)	-			
Typo	Tape width (mm)	-			
Туре	Basic ordering unit (pcs)	450			
	Taping code	C9			
	Marking	R6046FNZ1			

● Absolute maximum ratings(T_a = 25°C)

Paramete	Symbol	Value	Unit	
Drain - Source voltage		V_{DSS}	600	V
Continuous dusin suurent	T _c = 25°C	I _D *1	±46	А
Continuous drain current	T _c = 100°C	I _D *1	±23	А
Pulsed drain current	I _{D,pulse} *2	±115	А	
Gate - Source voltage		V_{GSS}	±30	V
Avalanche energy, single pulse		E _{AS} *3	142	mJ
Avalanche energy, repetitive		E _{AR} *4	5.4	mJ
Avalanche current		I _{AR} *3	23	А
Power dissipation $(T_c = 25^{\circ}C)$		P _D	694	W
Junction temperature		T _j	150	°C
Range of storage temperature		T _{stg}	−55 to +150	°C
Reverse diode dv/dt		dv/dt *5	15	V/ns

Absolute maximum ratings

Parameter	Symbol	Conditions	Values	Unit
Drain - Source voltage slope	dv/dt	$V_{DS} = 480V, I_{D} = 46A$ $T_{j} = 125^{\circ}C$	50	V/ns

●Thermal resistance

Parameter	Symbol	Values			Unit
- Farameter	Symbol	Min.	Тур.	Max.	Offic
Thermal resistance, junction - case	R_{thJC}	-	-	0.18	°C/W
Thermal resistance, junction - ambient	R_{thJA}	-	-	30	°C/W
Soldering temperature, wavesoldering for 10s	T_{sold}	-	-	265	°C

•Electrical characteristics($T_a = 25$ °C)

Parameter	Symbol	Conditions	Values			Unit
raiametei	Syllibol	Conditions	Min.	Тур.	Max.	Offic
Drain - Source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V$, $I_D = 1mA$	600	1	-	V
Drain - Source avalanche breakdown voltage	$V_{(BR)DS}$	$V_{GS} = 0V, I_D = 46A$	-	700	-	V
Zero gate voltage		$V_{DS} = 600V, V_{GS} = 0V$				μА
drain current	I _{DSS}	T _j = 25°C	-	1	100	
		T _j = 125°C	-	-	100	mA
Gate - Source leakage current	I_{GSS}	$V_{GS} = \pm 30V, V_{DS} = 0V$	-	ı	±100	nA
Gate threshold voltage	V _{GS (th)}	$V_{DS} = 10V$, $I_D = 1mA$	3	-	5	V
		$V_{GS} = 10V, I_D = 23A$				
Static drain - source on - state resistance	R _{DS(on)} *6	T _j = 25°C	-	0.075	0.098	Ω
		T _j = 125°C	-	0.16	-	
Gate input resistance	R_{G}	f = 1MHz, open drain	-	1.7	-	Ω

●Electrical characteristics(T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Transconductance	g _{fs} *6	$V_{DS} = 10V, I_{D} = 23A$	15	31	-	S
Input capacitance	C _{iss}	V _{GS} = 0V	-	6230	-	
Output capacitance	C _{oss}	V _{DS} = 25V	-	4000	-	pF
Reverse transfer capacitance	C_{rss}	f = 1MHz	-	85	-	
Effective output capacitance, energy related	$C_{\text{o(er)}}$	$V_{GS} = 0V$	-	175	•	٦.
Effective output capacitance, time related	$C_{o(tr)}$	V _{DS} = 0V to 480V	-	596	-	pF
Turn - on delay time	t _{d(on)} *6	$V_{DD} \simeq 300V$, $V_{GS} = 10V$	-	73	-	
Rise time	t _r *6	I _D = 23A	-	120	-	no
Turn - off delay time	t _{d(off)} *6	$R_L = 13.0\Omega$	-	240	480	ns
Fall time	t _f *6	$R_G = 10\Omega$	-	68	136	

•Gate Charge characteristics($T_a = 25$ °C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Total gate charge	Qg *6	$V_{DD} \simeq 300V$	-	150	1	
Gate - Source charge	Q _{gs} *6	I _D = 46A	-	40	-	nC
Gate - Drain charge	Q _{gd} *6	V _{GS} = 10V	-	65	-	
Gate plateau voltage	$V_{(plateau)}$	$V_{DD} \simeq 300V$, $I_D = 46A$	-	7.1	-	V

^{*1} Limited only by maximum temperature allowed.

*6 Pulsed

^{*2} $P_W \le 10 \mu s$, Duty cycle $\le 1\%$

^{*3} L $^{\simeq}$ 500 μ H, V_{DD} = 50V, R_{G} = 25 Ω , starting T_{j} = 25°C

^{*4} L $^{\sim}$ 500 μ H, V_{DD} = 50V, R_G = 25 Ω , starting T_j = 25°C, f = 10kHz

^{*5} Reference measurement circuits Fig.5-1.

●Body diode electrical characteristics (Source-Drain)(T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
r ai ai nietei	Symbol	Conditions	Min.	Тур.	Max.	Offic
Inverse diode continuous, forward current	I _S *1	T _c = 25°C	-	,	46	А
Inverse diode direct current, pulsed	I _{SM} *2	1 c = 20 0	-	-	115	А
Forward voltage	V _{SD} *6	$V_{GS} = 0V, I_{S} = 46A$	-	-	1.5	V
Reverse recovery time	t _{rr} *6		-	145	-	ns
Reverse recovery charge	Q _{rr} *6	I _S = 46A di/dt = 100A/us	-	0.74	-	μС
Peak reverse recovery current	I _{rrm} *6		-	9.6	-	А
Peak rate of fall of reverse recovery current	di _{rr} /dt	T _j = 25°C	-	1200	-	A/μs

● Typical Transient Thermal Characteristics

Symbol	Value	Unit
R _{th1}	0.055	
R _{th2}	0.164	K/W
R _{th3}	0.821	

Symbol	Value	Unit
C _{th1}	0.0236	
C _{th2}	0.134	Ws/K
C _{th3}	1.09	

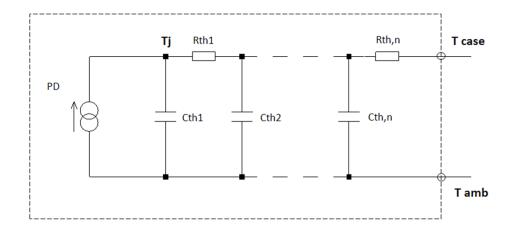
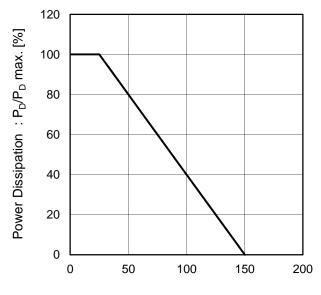
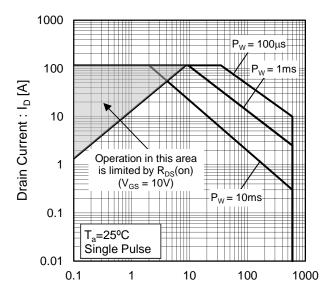


Fig.1 Power Dissipation Derating Curve

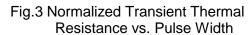


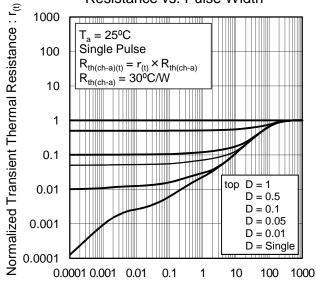
Junction Temperature : T_i [°C]

Fig.2 Maximum Safe Operating Area



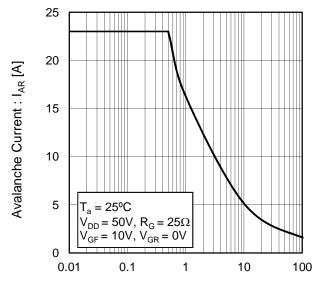
Drain - Source Voltage : V_{DS} [V]





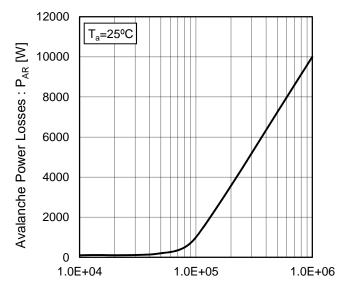
Pulse Width: Pw [s]

Fig.4 Avalanche Current vs Inductive Load



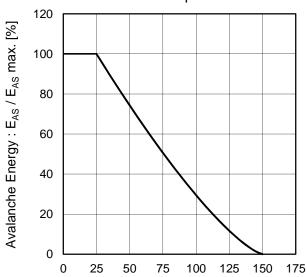
Coil Inductance: L [mH]

Fig.5 Avalanche Power Losses



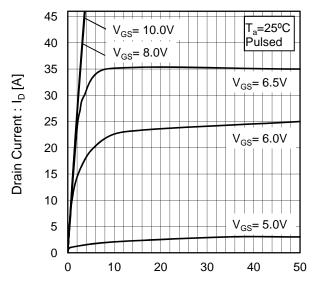
Frequency: f [Hz]

Fig.6 Avalanche Energy Derating Curve vs Junction Temperature



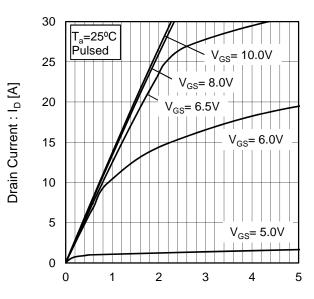
Junction Temperature : T_i [°C]

Fig.7 Typical Output Characteristics(I)



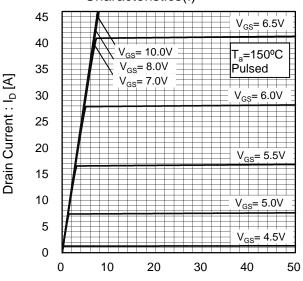
Drain - Source Voltage : V_{DS} [V]

Fig.8 Typical Output Characteristics(II)



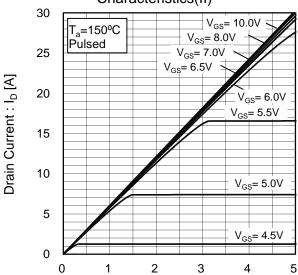
Drain - Source Voltage : V_{DS} [V]

Fig.9 $T_j = 150^{\circ}C$ Typical Output Characteristics(I)



Drain - Source Voltage : V_{DS} [V]

Fig.10 T_j = 150°C Typical Output Characteristics(II)



Drain - Source Voltage : V_{DS} [V]

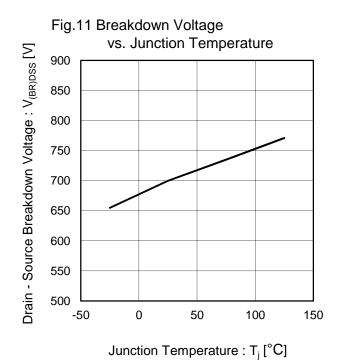
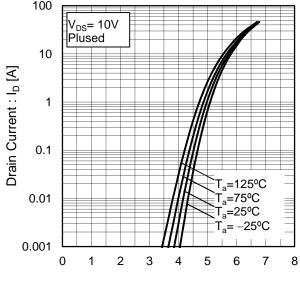


Fig.12 Typical Transfer Characteristics



Gate - Source Voltage : V_{GS} [V]

Fig.13 Gate Threshold Voltage vs. Junction Temperature 5 $V_{DS} = 10V$ Gate Threshold Voltage : $V_{GS(th)}\left[V\right]$ I_D= 1mA Plused 4 3 -50 -25 0 25 50 75 100 125 150 Junction Temperature : T_i [°C]

Fig.14 Transconductance vs. Drain Current

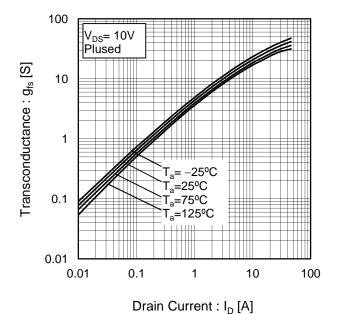
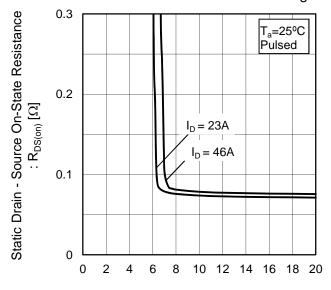
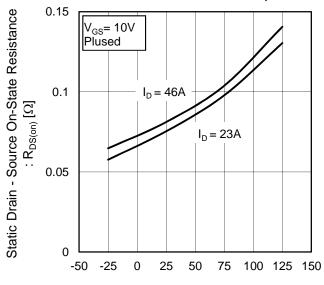


Fig.15 Static Drain - Source On - State Resistance vs. Gate Source Voltage



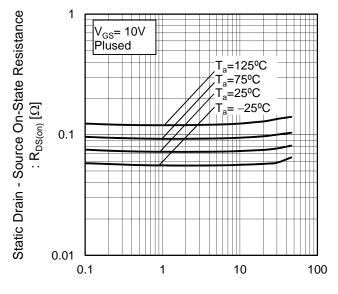
Gate - Source Voltage : V_{GS} [V]

Fig.16 Static Drain - Source On - State Resistance vs. Junction Temperature



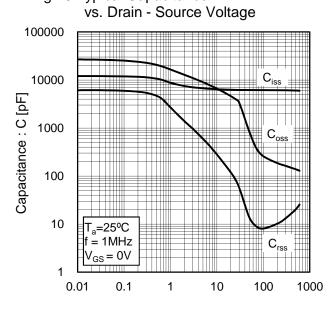
Junction Temperature : T_i [°C]

Fig.17 Static Drain - Source On - State Resistance vs. Drain Current



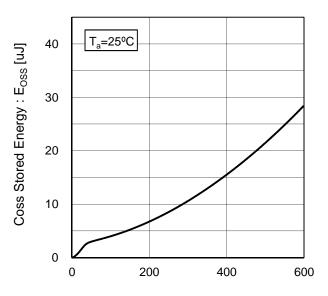
Drain Current : I_D [A]

Fig.18 Typical Capacitance



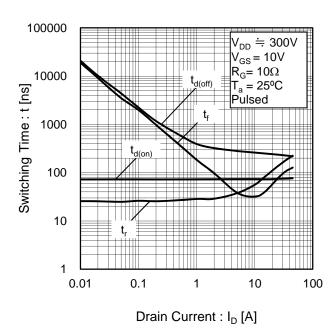
Drain - Source Voltage : V_{DS} [V]

Fig.19 Coss Stored Energy



Drain - Source Voltage : V_{DS} [V]

Fig.20 Switching Characteristics



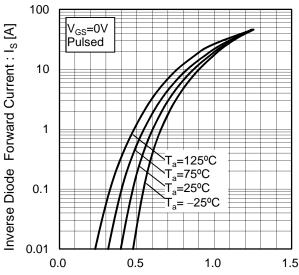
Gate - Source Voltage : V_{GS} [V]

T_a = 25°C V_{DD}= 300V I_D= 46A Pulsed 0 0 20 40 60 80 100 120 140 160

Fig.21 Dynamic Input Characteristics

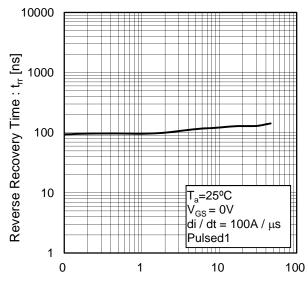
Total Gate Charge : Q_g [nC]

Fig.22 Inverse Diode Forward Current vs. Source - Drain Voltage



Source - Drain Voltage : V_{SD} [V]

Fig.23 Reverse Recovery Time vs.Inverse Diode Forward Current



Inverse Diode Forward Current : I_S [A]

Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

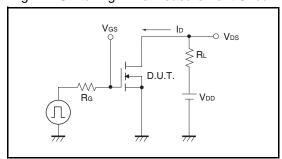


Fig.2-1 Gate Charge Measurement Circuit

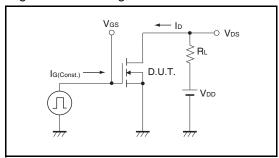


Fig.3-1 Avalanche Measurement Circuit

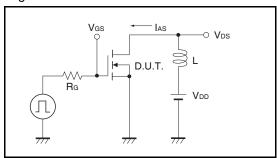


Fig.4-1 dv/dt Measurement Circuit

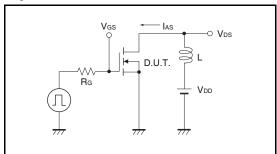


Fig.5-1 di/dt Measurement Circuit

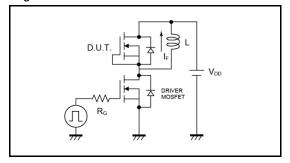


Fig.1-2 Switching Waveforms

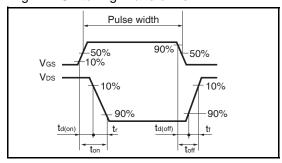


Fig.2-2 Gate Charge Waveform

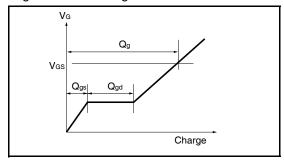


Fig.3-2 Avalanche Waveform

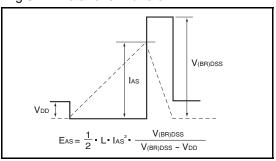


Fig.4-2 dv/dt Waveform

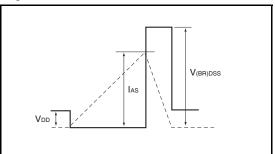
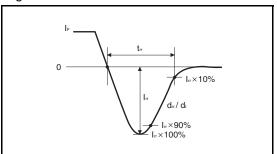
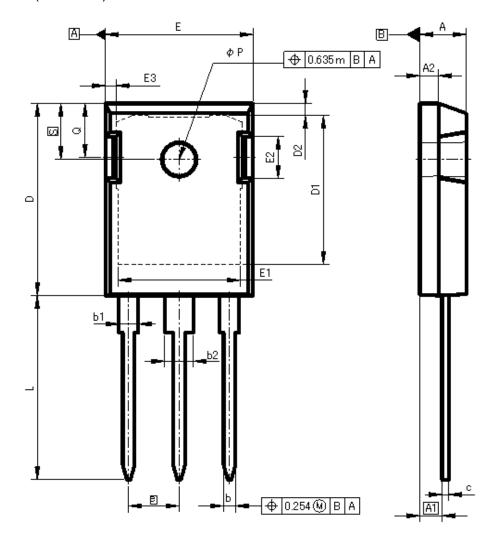


Fig.5-2 di/dt Waveform



●Dimensions (Unit : mm)

TO-247



DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.83	5.21	0.190	0.205
A1	2.29	2.54	0.090	0.100
A2	1.91	2.16	0.075	0.085
b	1.14	1.40	0.045	0.055
b1	1.91	2.20	0.075	0.087
b2	2.92	3.20	0.115	0.126
С	0.61	0.80	0.024	0.031
D	20.80	21.34	0.819	0.840
D1	17.43	17.83	0.686	0.702
Е	15.75	16.13	0.620	0.635
е	5.45		0.2	15
N	3.0	00	3.0	00
L	19.81	20.57	0.780	0.810
L1	3.81	4.32	0.150	0.170
ФР	3.55	3.65	0.140	0.144
Q	5.59	6.20	0.220	0.244
S	6.	15	0.2	40

Dimension in mm / inches

Notice

Precaution on using ROHM Products

1. Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JÁPAN	USA	EU	CHINA
CLASSⅢ	CLASSII	CLASS II b	CLASSIII
CLASSIV		CLASSⅢ	

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
 - [a] Installation of protection circuits or other protective devices to improve system safety
 - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
 - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

Precaution for Foreign Exchange and Foreign Trade act

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

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